TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7PA34FU

#### **Dual Non-Inverter**

#### **Features**

- Operating voltage range: V<sub>CC</sub> = 1.8 to 3.6 V
- High-speed operation:  $t_{pd}$  = 3.5 ns (max) at  $V_{CC}$  = 3.0 to 3.6 V

 $t_{pd}$  = 4.2 ns (max) at  $V_{CC}$  = 2.3 to 2.7 V

 $t_{pd}$  = 8.4 ns (max) at  $V_{CC}$  = 1.8 V

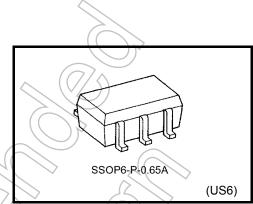
· High-level output current:

 $I_{OH}/I_{OL}$  = ±24 mA (min) at  $V_{CC}$  = 3.0 V

 $I_{OH}/I_{OL}$  = ±18 mA (min) at  $V_{CC}$  = 2.3 V

 $I_{OH}/I_{OL}$  = ±6 mA (min) at  $V_{CC}$  = 1.8 V

- 3.6-V tolerant inputs.
- 3.6-V power down protection outputs.

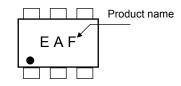


Weight: 0.0068 g (typ.)

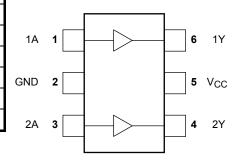
#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	-0.5 to 4.6	V
DC input voltage	V <sub>IN</sub> (	-0.5 to 4.6	V
DC output voltage	Vou	-0.5 to 4.6 (Note 1)	1)
DC output voitage	Vou	-0.5 to V <sub>CC</sub> + 0.5 (Note 2)	>
Input diode current	) <u>¥</u>	-50	mA
Output diode current	lok	-50 (Note 3)	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±100	mA
Power dissipation	PD	200	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C
		. 1	

#### Marking



### Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V<sub>CC</sub> = 0 V

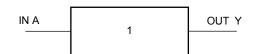
Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

Start of commercial production 2001-09

## **IEC Logic Symbol**

#### **Truth Table**



А	Y
L	L
Н	Н

## **Operating Ranges**

Characteristics	Symbol	Rating
Supply voltage	Voo	1.8 to 3.6
Supply voltage	V <sub>CC</sub>	1.2 to 3.6 (Note 4)
Input voltage	V <sub>IN</sub>	-0.3 to 3.6 V
Output voltage	Vour	0 to 3.6 (Note 5)
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub> (Note 6)
		±24 (Note 7)
Output Current	I <sub>OH</sub> /I <sub>OL</sub>	±18 (Note 8) mA
		±6 (Note 9)
Operating temperature	T <sub>opr</sub>	-40 to 85 °C
Input rise and fall time	d <sub>t</sub> /d <sub>v</sub>	0 to 10 (Note 10) ns/V

Note 4: Data retention only

Note 5:  $V_{CC} = 0 V$ 

Note 6: High or Low state

Note 7:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 8:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$ 

Note 9:  $V_{CC} = 1.8 \text{ V}$ 

Note 10:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



#### **Electrical Characteristics**

#### DC Characteristics (Ta = -40 to 85°C, 2.7 V < V<sub>CC</sub>≤ 3.6 V)

Chara	acteristics	Symbol	Test Condition V <sub>CC</sub> (		V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	High level	V <sub>IH</sub>		_	2.7 to 3.6	2.0	_	V
Input voltage	Low level	V <sub>IL</sub>		_	2.7 to 3.6	_	0.8	V
			V <sub>OH</sub> V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	_	
	High level	V <sub>OH</sub>		I <sub>OH</sub> = -12 mA	2.7	2.2	_	V
Output Voltage				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
				$I_{OH} = -24 \text{ mA}$	3.0	2.2		
			V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7 to 3.6		0.2	
	Low level			I <sub>OL</sub> = 12 mA	2.7	*	0.4	
	Low level	V <sub>OL</sub>	VIN - VIL	I <sub>OL</sub> = 18 mA	3.0		0.4	
			$I_{OL} = 24$	$I_{OL} = 24 \text{ mA}$	3.0		0.55	
Input Leakage Cu	ırrent	I <sub>IN</sub>	$V_{IN} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6	H	±5.0	μΑ
Power-off Leakag	je Current	I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to	3.6 V	0	>)	10.0	μΑ
Ouioscont Supply Current		Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6		20.0	
Quiescent Supply	Quiescent Supply Current		V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		2.7 to 3.6		±20.0	μΑ
Increase in I <sub>CC</sub> pe	er Input	Δl <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6	V	2.7 to 3.6	_	750	

## DC Characteristics (Ta = -40 to 85°C, 2.3 V≤ V<sub>CC</sub>≤ 2.7 V)

Charac	teristics	Symbol	Test Condition		\/aa (\/)	Min	Max	Unit
	I	7/4			V <sub>CC</sub> (V)			
Input voltage	High level	// <b>(</b> VIH		4	2.3 to 2.7	1.6	_	V
put voltage	Low level	√V <sub>IL</sub>	(7)		2.3 to 2.7	_	0.7	·
				I <sub>OH</sub> = -100 μA	2.3 to 2.7	V <sub>CC</sub> - 0.2		
	High level	VoH	$V_{IN} = V_{IH}$	$I_{OH} = -6 \text{ mA}$	2.3	2.0		V
	\frac{1}{2}			$I_{OH} = -12 \text{ mA}$	2.3	1.8		
Output Voltage		$\wedge$		$I_{OH} = -18 \text{ mA}$	2.3	1.7	_	
6		Vol	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.3 to 2.7		0.2	V
	Low level			I <sub>OL</sub> = 12 mA	2.3	_	0.4	V
				I <sub>OL</sub> = 18 mA	2.3		0.6	
Input Leakage Curr	rent	JIN	$V_{IN} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7		±5.0	μΑ
Power-off Leakage	Current	loff	$V_{IN}$ , $V_{OUT} = 0$ to 3	3.6 V	0	_	10.0	μА
Quioscont Supply (	Current	loo	V <sub>IN</sub> = V <sub>CC</sub> or GNI	)	2.3 to 2.7	_	20.0	^
Quiescent Supply (	Juli Glit	Icc	V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub>	)≤ 3.6 V	2.3 to 2.7	_	±20.0	μА

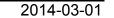
## DC Characteristics (Ta = -40 to $85^{\circ}$ C, $1.8 \text{ V} \le \text{V}_{CC} < 2.3 \text{ V}$ )

Chara	cteristics	Symbol	Test C	condition	V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	High level	V <sub>IH</sub>	_		1.8 to 2.3	V <sub>CC</sub> × 0.7		V
input voitage	Low level	VIL			1.8 to 2.3	_	V <sub>CC</sub> × 0.2	V
	High level	Voh	V <sub>OH</sub> V <sub>IN</sub> = V <sub>IH</sub>		1.8	VCC 0.2	_	
Output Voltage		0		I <sub>OH</sub> = -6 mA	7/1,8	1.4	_	V
	Low level	Voi	$V_{IN} = V_{IL}$	$I_{OL} = 100 \mu A$	1.8	_	0.2	
	Low level	V <sub>OL</sub>		I <sub>OL</sub> = 6 mA	1.8		0.3	
Input Leakage Cui	rrent	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.8	1	±5.0	μΑ
Power-off Leakage	e Current	l <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	A ( )	10.0	μА
Quiescent Supply Current		loo	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.8	173	20.0	μА
Quiescent Supply	Ourient	Icc	V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		1.8	)}-	±20.0	μΛ

## AC Characteristics (Ta = -40 to 85°C, input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ $\Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
	<b>+</b>		1.8	1.0	8.4	
Propagation delay time	t <sub>pLH</sub>	(Figure 1 and 2)	2.5 ± 0.2	8.0	4.2	ns
	t <sub>pHL</sub>		$3.3 \pm 0.3$	0.6	3.5	

For  $C_L = 50$  pF, add approximately 300 ps to the AC maximum specification.



## Dynamic Switching Characteristics (Ta = 25°C, input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition			Тур.	Unit		
	<b>-</b>	root condition				V <sub>CC</sub> (V)	. 7 [-	J,
		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 11)	1.8	0.25			
Quiet Output Maximum Dynamic VOL	$V_{OLP}$	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 11)	2.5	0.6	V		
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 11)	3.3	0.8			
		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 11)	1,8	-0.25			
Quiet Output Minimum Dynamic V <sub>OL</sub>	$V_{OLV}$	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 11)	2.5	-0.6	V		
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 11)	3.3	-0.8			
		V <sub>IN</sub> = 1.8 V, V <sub>IL</sub> = 0 V	(Note 11)	1.8	1.5			
Quiet Output Minimum Dynamic V <sub>OH</sub>	$V_{OLP}$	V <sub>IN</sub> = 2.5 V, V <sub>IL</sub> = 0 V	(Note 11)	2.5	1.9	V		
		V <sub>IN</sub> = 3.3 V, V <sub>IL</sub> = 0 V	(Note 11)	3.3	2.2			

Note 11: Characteristics guaranteed by design.

## **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	y <sub>cc</sub> (V)	Тур.	Unit
Input Capacitance	C <sub>IN</sub>		1.8, 2.5, 3.3	4	pF
Power Dissipation Capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz	(Note 12) 1.8, 2.5, 3.3	12	pF

Note 12: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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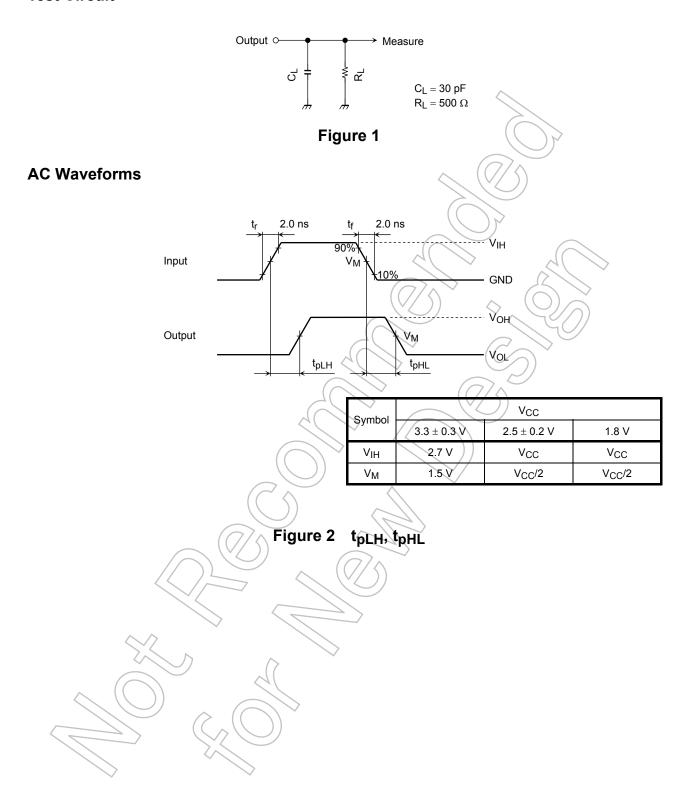
Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ 



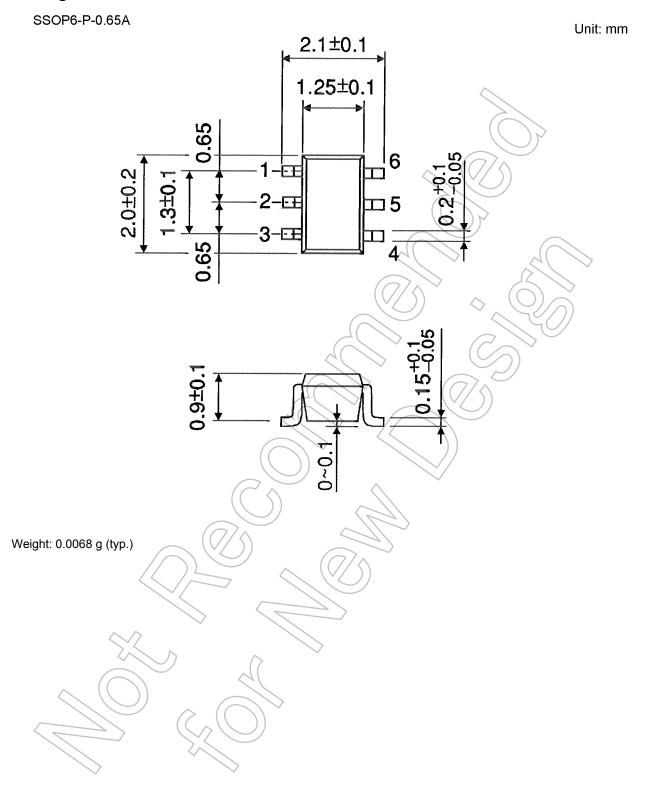
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#### **Test Circuit**



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## **Package Dimensions**



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